TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# 2SC3423

### Audio Frequency Amplifier Applications

- Complementary to 2SA1360
- Small collector output capacitance:  $C_{ob} = 1.8 \text{ pF}$  (typ.)
- High transition frequency:  $f_T = 200 \text{ MHz}$  (typ.)

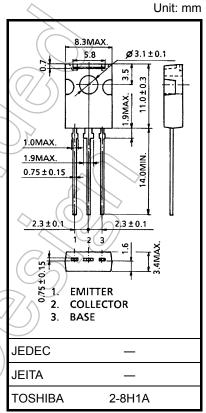
#### **Absolute Maximum Ratings (Tc = 25°C)**

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	150	(N)	
Collector-emitter voltage		V <sub>CEO</sub>	150		
Emitter-base voltage		V <sub>EBO</sub>	5	V	
Collector current		Ic	50	mA	
Base current		ΙΒ	5	mA	
Collector power dissipation	Ta = 25°C	PC	1.2	W	
	Tc = 25°C	- FC	55	VV	
Junction temperature		T <sub>j</sub>	150	⟨⟨c	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C/	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e.

operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



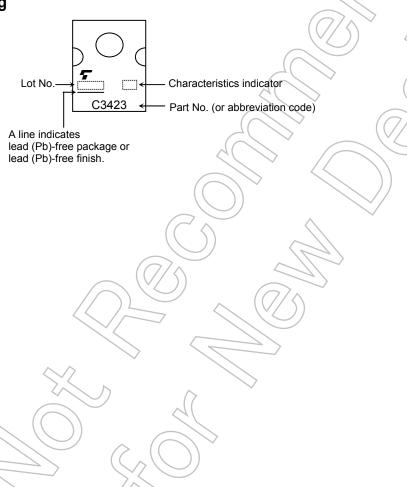
Weight: 0.82 g (typ.)

## Electrical Characteristics (Tc = 25°C)

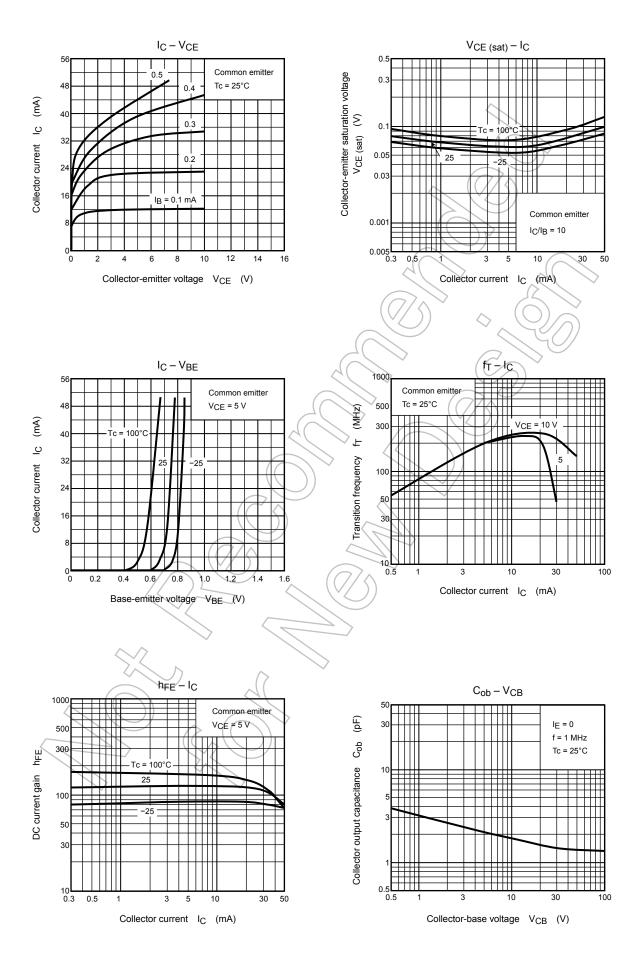
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 150 V, I <sub>E</sub> = 0	_	_	0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	_	0.1	μA
DC current gain	h <sub>FE</sub> (Note)	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 10 mA	80	1	240	
Collector-emitter saturation voltage	V <sub>CE</sub> (sat)	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 1 mA	1	) /~	1.0	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 10 mA	7	_	0.8	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 10 mA	()	200	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz		1.8	_	pF

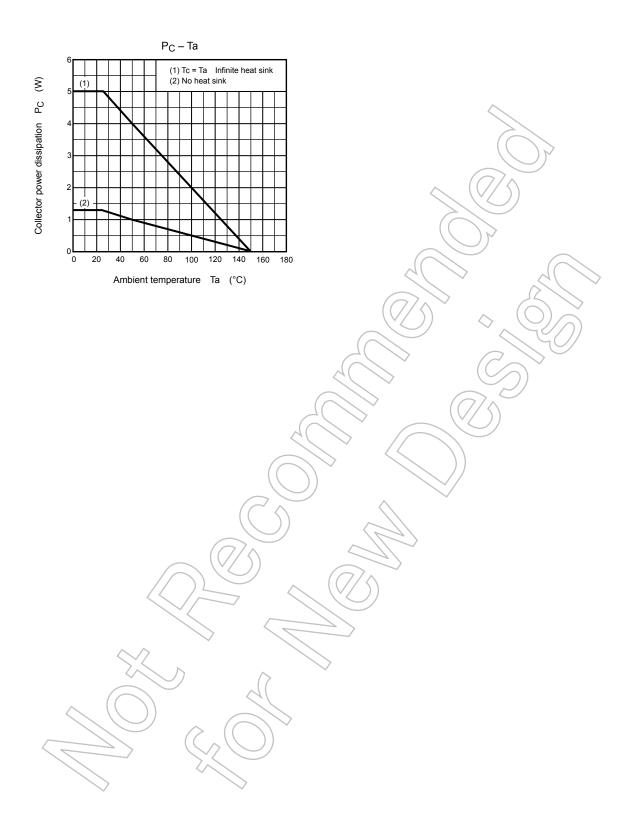
Note:  $h_{\mbox{\scriptsize FE}}$  classification O: 80 to 160, Y: 120 to 240





2 2006-11-09





4 2006-11-09



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